Technical Data Data Sheet 3458, Rev. A Green Products

# MBR1560CT-G/MBRB1560CT-G/MBR1560-1-G SCHOTTKY RECTIFIER

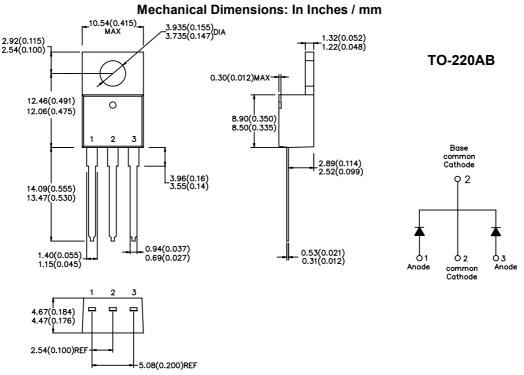
## **Applications:**

• Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection

#### Features:

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability

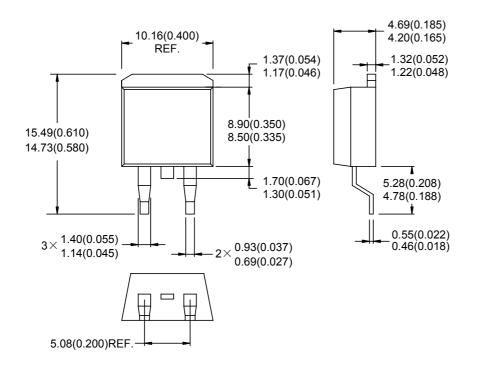


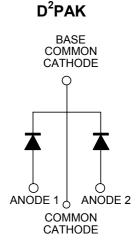


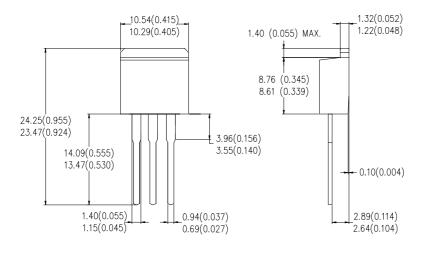
- 221 West Industry Court ☐ Deer Park, NY 11729-4681 ☐ (631) 586-7600 FAX (631) 242-9798
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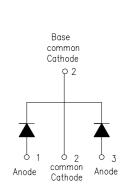
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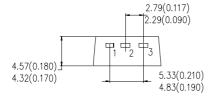








**TO-262** 



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## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	60	V
Max. Average Forward	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> = 125°C, rectangular wave form	15	Α
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	150	А

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	$V_{F1}$	@ 15A, Pulse, T <sub>J</sub> = 25 °C	0.90	V
	$V_{F2}$	@ 15A, Pulse, T <sub>J</sub> = 125 °C	0.80	V
Max. Reverse Current (per leg) *	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25  ^{\circ}\text{C}$	1.0	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 125^{\circ}C$	50	mA
Max. Junction Capacitance (per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	300	pF
Typical Series Inductance (per leg)	L <sub>S</sub>	Measured lead to lead 5 mm from package body	8.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

<sup>\*</sup> Pulse Width < 300µs, Duty Cycle <2%

## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	$T_J$	-	-55 to +150	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	2.0	°C/W
Maximum Thermal Resistance, Junction to Case(Per package)	$R_{ heta JC}$	DC operation	60	°C/W
Approximate Weight	wt	-	2	g
Mounting Torque	T <sub>M</sub>	-	6(Min.) 12(Max.)	Kg-cm
Case Style	TO-220AB D <sup>2</sup> PAK TO-262			

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# SENSITRON **SEMICONDUCTOR**

MBR1560CT-G MBRB1560CT-G MBR1560CT-1-G

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